NSN 5961-00-370-8516

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-370-8516

Inclosure Material:

Metal

Overall Length:

1.330 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-61

Mounting Method:

Threaded stud

Overall Width Across Flats:

0.677 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

170.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

static, collector open

Current Rating Per Characteristic:

10.00 amperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

22915-2t035 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0